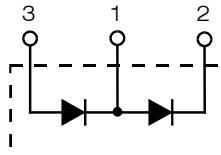


## Diode Modules

## PSKD 56

Preliminary Data Sheet

<b>V<sub>RSM</sub></b>	<b>V<sub>RRM</sub></b>	<b>Type</b>
<b>V</b>	<b>V</b>	
900	800	PSKD 56/08
1300	1200	PSKD 56/12
1500	1400	PSKD 56/14
1700	1600	PSKD 56/16
1900	1800	PSKD 56/18



**I<sub>FRMS</sub>** = 2x 150 A  
**I<sub>FAVM</sub>** = 2x 95 A  
**V<sub>RRM</sub>** = 800-1800 V



<b>Symbol</b>	<b>Test Conditions</b>		<b>Maximum Ratings</b>	
I <sub>FRMS</sub>	T <sub>vJ</sub> = T <sub>vJM</sub>		150	A
I <sub>FAVM</sub>	T <sub>c</sub> = 75°C; 180° sine		95	A
	T <sub>c</sub> = 100°C; 180° sine		71	A
I <sub>FSM</sub>	T <sub>vJ</sub> = 45°C; V <sub>R</sub> = 0	t = 10 ms (50 Hz), sine	1400	A
		t = 8.3 ms (60 Hz), sine	1650	A
	T <sub>vJ</sub> = T <sub>vJM</sub> ; V <sub>R</sub> = 0	t = 10 ms (50 Hz), sine	1200	A
		t = 8.3 ms (60 Hz), sine	1400	A
j <sup>2</sup> dt	T <sub>vJ</sub> = 45°C; V <sub>R</sub> = 0	t = 10 ms (50 Hz), sine	9800	A <sup>2</sup> s
		t = 8.3 ms (60 Hz), sine	11300	A <sup>2</sup> s
	T <sub>vJ</sub> = T <sub>vJM</sub> ; V <sub>R</sub> = 0	t = 10 ms (50 Hz), sine	7200	A <sup>2</sup> s
		t = 8.3 ms (60 Hz), sine	8100	A <sup>2</sup> s
T <sub>vJ</sub>			-40...+150	°C
T <sub>vJM</sub>			150	°C
T <sub>stg</sub>			-40...+125	°C
V <sub>ISOL</sub>	50/60 Hz, RMS	t = 1 min	3000	V~
	I <sub>ISOL</sub> ≤ 1 mA	t = 1 s	3600	V~
M <sub>d</sub>	Mounting torque (M5)		2.5-4/22-35 Nm/lb.in.	
	Terminal connection torque (M5)		2.5-4/22-35 Nm/lb.in.	
Weight	Typical including screws		90	g
<b>Symbol</b>	<b>Test Conditions</b>		<b>Characteristic Values</b>	
I <sub>R</sub>	T <sub>vJ</sub> = T <sub>vJM</sub> ; V <sub>R</sub> = V <sub>RRM</sub>		10	mA
V <sub>F</sub>	I <sub>F</sub> = 200 A; T <sub>vJ</sub> = 25°C		1.48	V
V <sub>T0</sub>	For power-loss calculations only		0.8	V
r <sub>T</sub>	T <sub>vJ</sub> = T <sub>vJM</sub>		3	mΩ
Q <sub>S</sub>	T <sub>vJ</sub> = 125°C; I <sub>F</sub> = 50 A, -di/dt = 3 A/μs		100	μC
I <sub>RM</sub>			24	A
R <sub>thJC</sub>	per diode; DC current		0.51	K/W
	per module	} other values see Fig. 6/7	0.255	K/W
R <sub>thJK</sub>	per diode; DC current		0.71	K/W
	per module		0.355	K/W
d <sub>s</sub>	Creepage distance on surface		12.7	mm
d <sub>A</sub>	Strike distance through air		9.6	mm
a	Maximum allowable acceleration		50	m/s <sup>2</sup>

Data according to IEC 60747 and refer to a single thyristor/diode unless otherwise stated.

### Features

- International standard package JEDEC TO-240 AA
- Direct copper bonded Al<sub>2</sub>O<sub>3</sub>-ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 148688

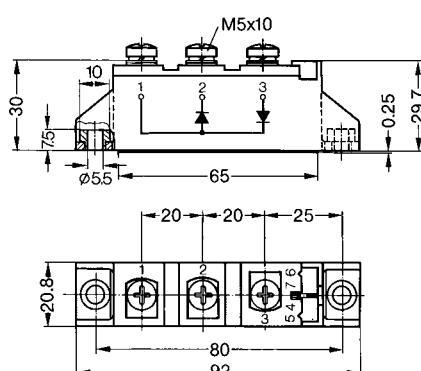
### Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

### Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

### Dimensions in mm (1 mm = 0.0394")



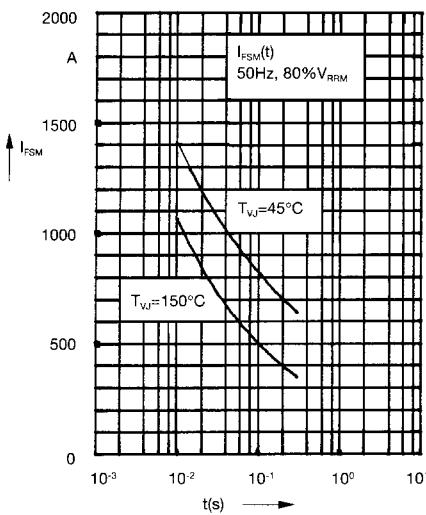


Fig. 1 Surge overload current  
 $I_{FSM}$ : Crest value,  $t$ : duration

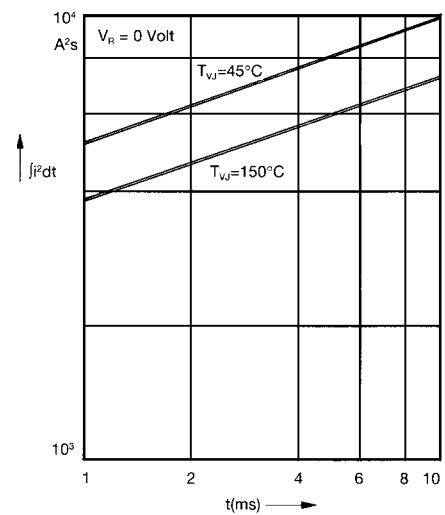


Fig. 2  $\int I^2 dt$  versus time (1-10 ms)

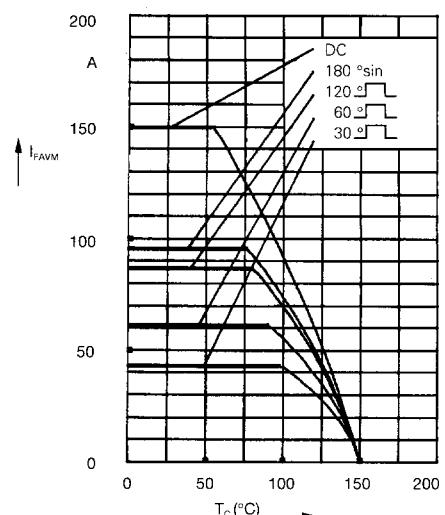


Fig. 2a Maximum forward current at case temperature

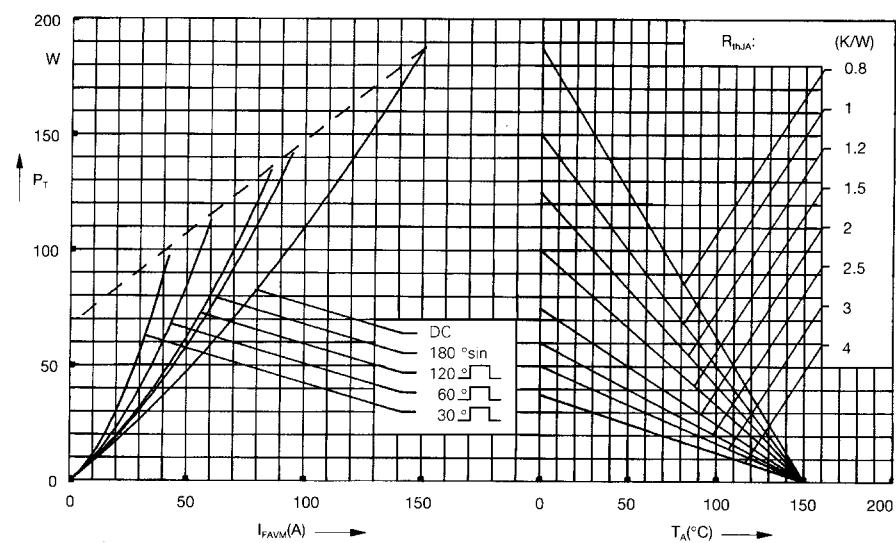


Fig. 3 Power dissipation versus forward current and ambient temperature (per diode)

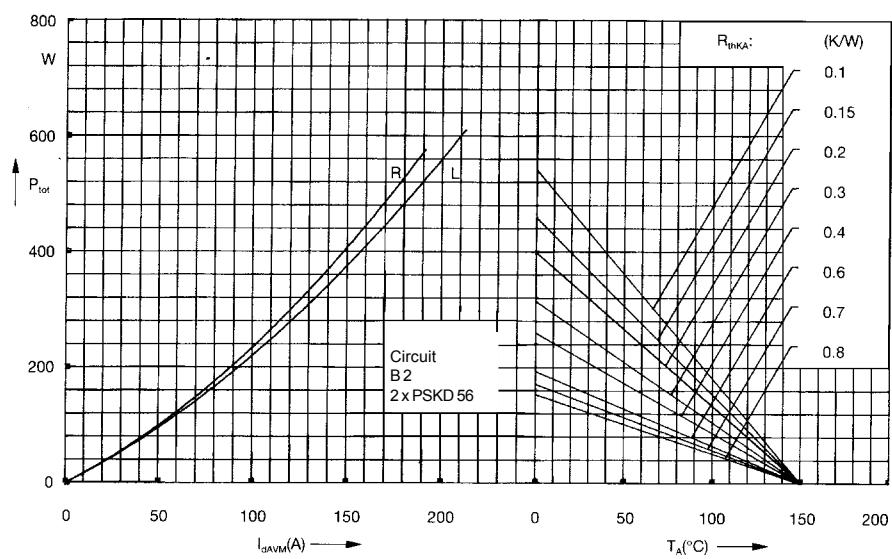


Fig. 4 Single phase rectifier bridge:  
Power dissipation versus direct output current and ambient temperature  
R = resistive load  
L = inductive load

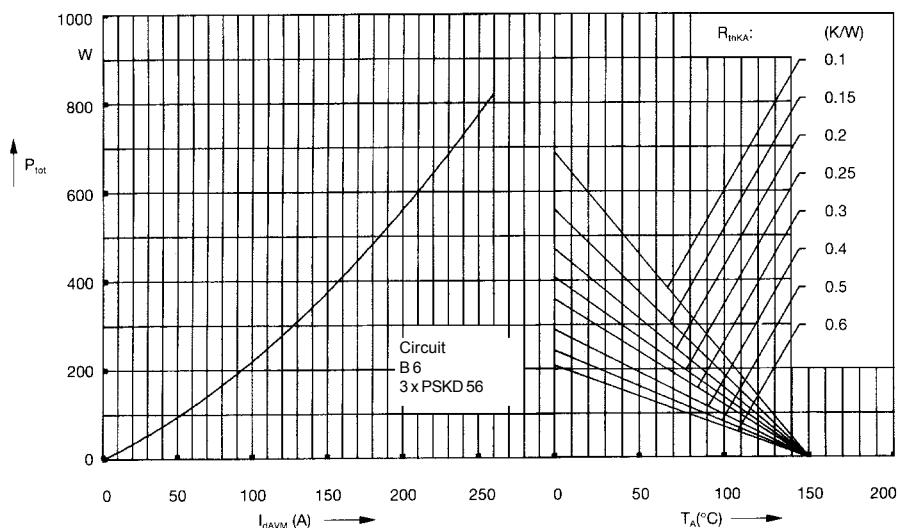


Fig. 5 Three phase rectifier bridge:  
Power dissipation versus direct  
output current and ambient  
temperature

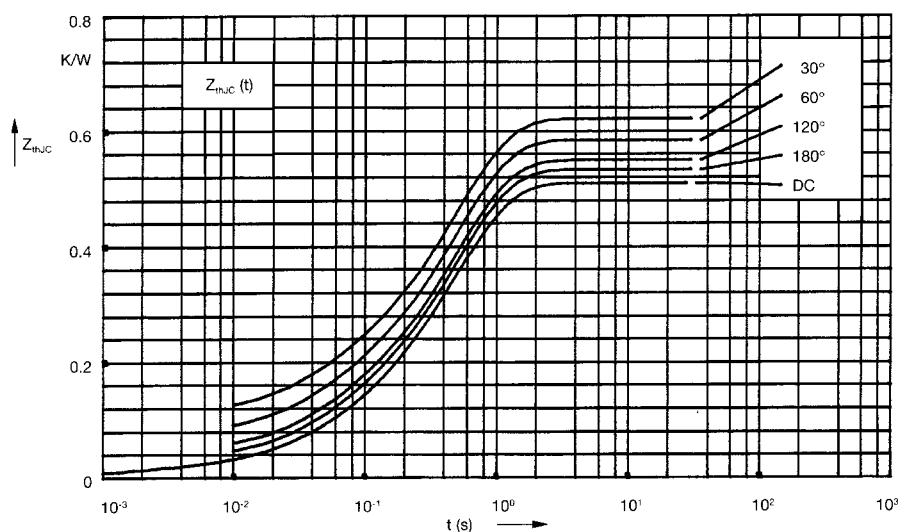


Fig. 6 Transient thermal impedance  
junction to case (per diode)

$R_{thJC}$  for various conduction angles d:

d	$R_{thJC}$ (K/W)
DC	0.51
180°	0.53
120°	0.55
60°	0.58
30°	0.62

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.013	0.0015
2	0.055	0.045
3	0.442	0.485

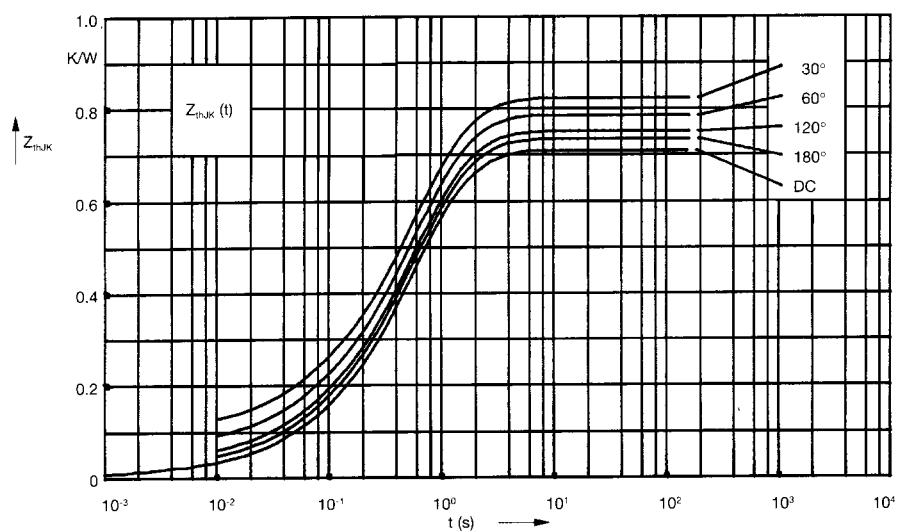


Fig. 7 Transient thermal impedance  
junction to heatsink (per diode)

$R_{thJK}$  for various conduction angles d:

d	$R_{thJK}$ (K/W)
DC	0.71
180°	0.73
120°	0.75
60°	0.78
30°	0.82

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.013	0.0015
2	0.055	0.045
3	0.442	0.485
4	0.2	1.25